

SEMICONDUCTOR DEVICE AND
METHOD OF MANUFACTURING THE SAME

ABSTRACT OF THE DISCLOSURE

In a semiconductor device and a method of manufacturing the semiconductor device, the source wires 126 of a pixel portion 205 are formed of material having low resistance (representatively, aluminum, silver, copper). The source wires of a driving circuit are formed in the same process as the gate wires 162 of the pixel portion and a pixel electrode 163.